



SANYO Semiconductors

DATA SHEET

2SK2625ALS

N-Channel Silicon MOSFET
General-Purpose Switching Device
Applications

Features

- Low ON-resistance.
- Low Qg.
- Ultrahigh-speed switching.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		600	V
Gate-to-Source Voltage	VGSS		±30	V
Drain Current (DC)	IDC*1	Limited only by maximum temperature	5	A
	IDpack*2	Tc=25°C (SANYO's ideal heat dissipation condition)*3	4.4	A
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	16	A
Allowable Power Dissipation	PD		2.0	W
		Tc=25°C (SANYO's ideal heat dissipation condition)*3	30	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C
Avalanche Energy (Single Pulse) *4	EAS		87	mJ
Avalanche Current *5	I _{AV}		4	A

*1 Shows chip capability

*2 Package limited

*3 SANYO's condition is radiation from backside.

The method is applying silicone grease to the backside of the device and attaching the device to water-cooled radiator made of aluminium.

*4 V_{DD}=50V, L=10mH, I_{AV}=4A

*5 L≤10mH, single pulse

Marking : K2625

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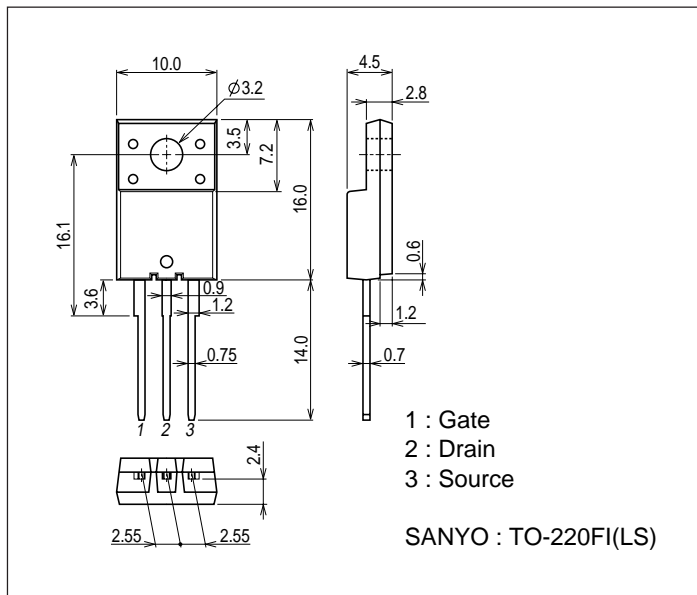
2SK2625ALS

Electrical Characteristics at Ta=25°C

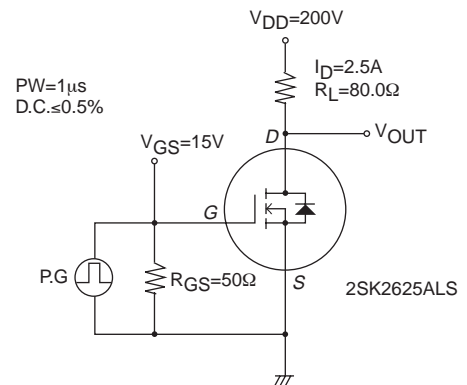
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D=1mA, V_{GS}=0V$	600			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS}=600V, V_{GS}=0V$			1.0	mA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 30V, V_{DS}=0V$			± 100	nA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS}=10V, I_D=1mA$	3.5		5.5	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS}=10V, I_D=2.5A$	1.5	3.0		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)}$	$I_D=2.5A, V_{GS}=15V$		1.5	2.0	Ω
Input Capacitance	C_{iss}	$V_{DS}=20V, f=1MHz$		700		pF
Output Capacitance	C_{oss}	$V_{DS}=20V, f=1MHz$		220		pF
Reverse Transfer Capacitance	C_{rss}	$V_{DS}=20V, f=1MHz$		110		pF
Total Gate Charge	Q_g	$V_{DS}=200V, I_D=5A, V_{GS}=10V$			20	nC
Turn-ON Delay Time	$t_d(on)$	See specified Test Circuit.		20		ns
Rise Time	t_r	See specified Test Circuit.		20		ns
Turn-OFF Delay Time	$t_d(off)$	See specified Test Circuit.		50		ns
Fall Time	t_f	See specified Test Circuit.		25		ns
Diode Forward Voltage	V_{SD}	$I_S=5A, V_{GS}=0V$		0.88	1.2	V

Package Dimensions

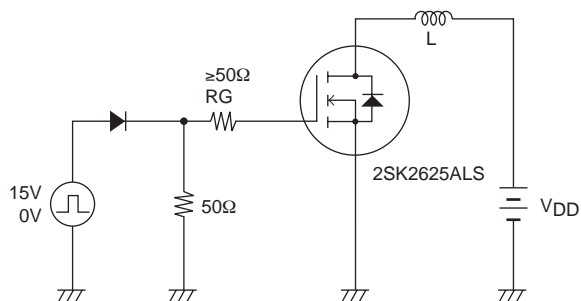
unit : mm (typ)
7509-002



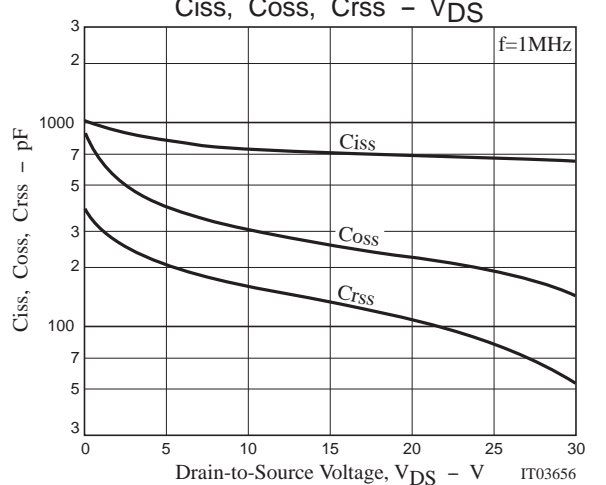
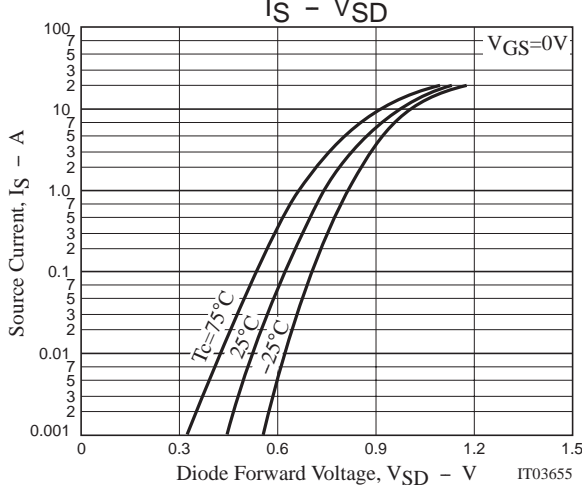
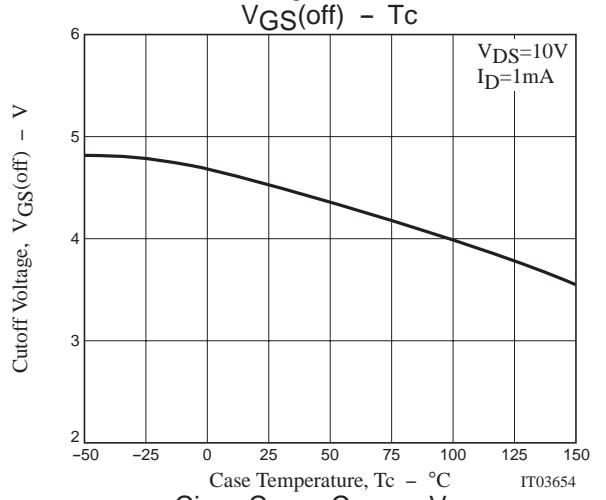
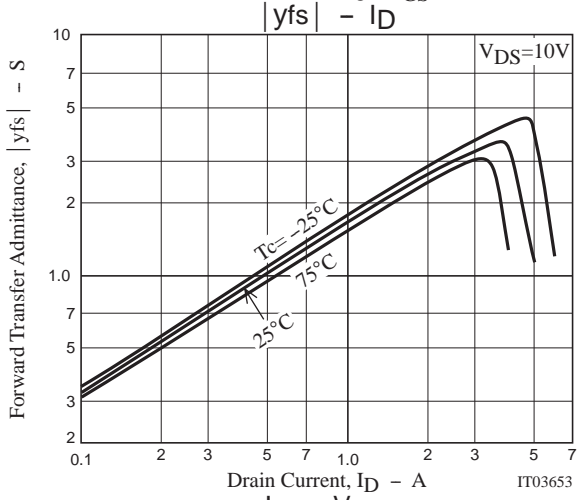
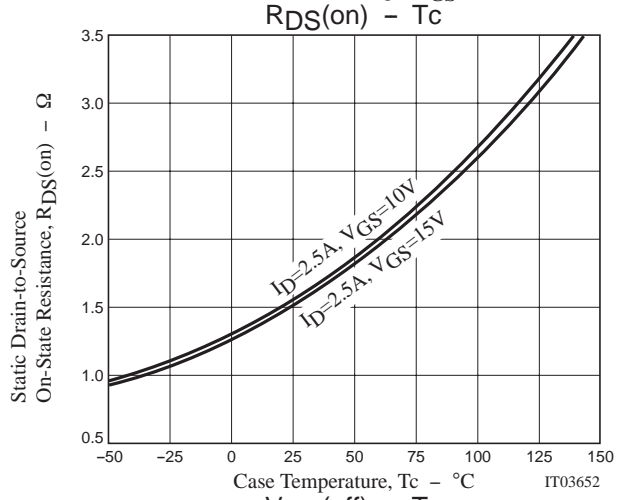
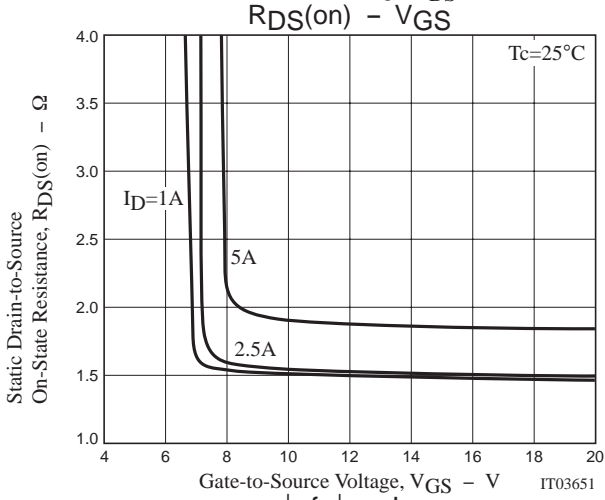
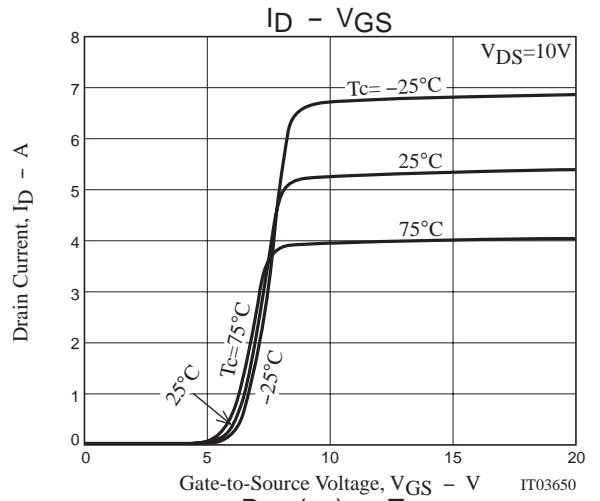
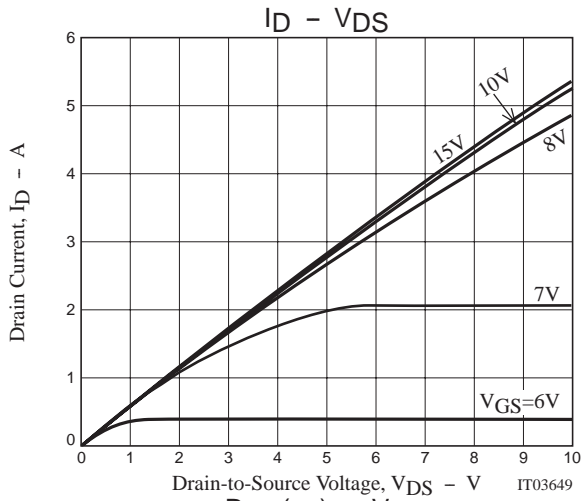
Switching Time Test Circuit



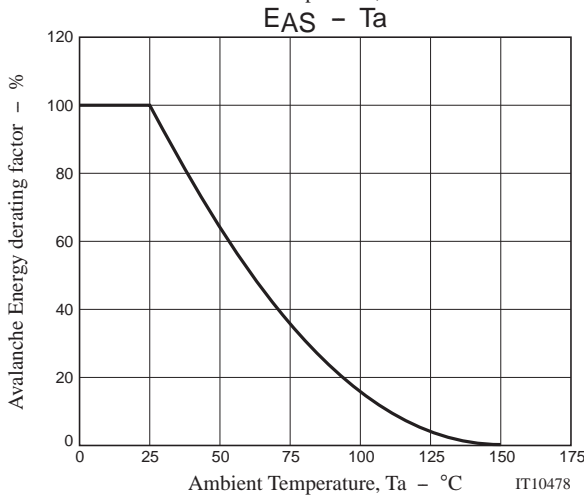
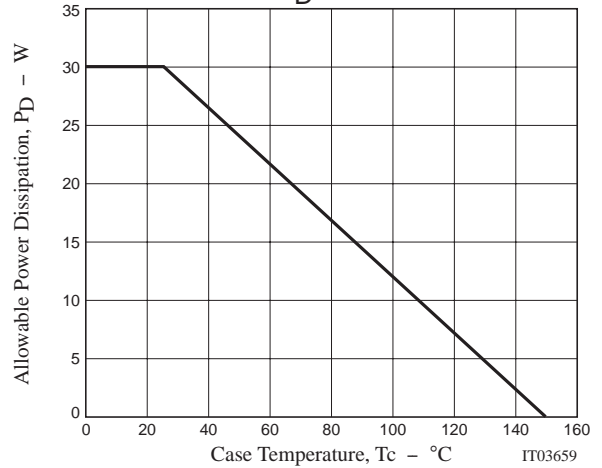
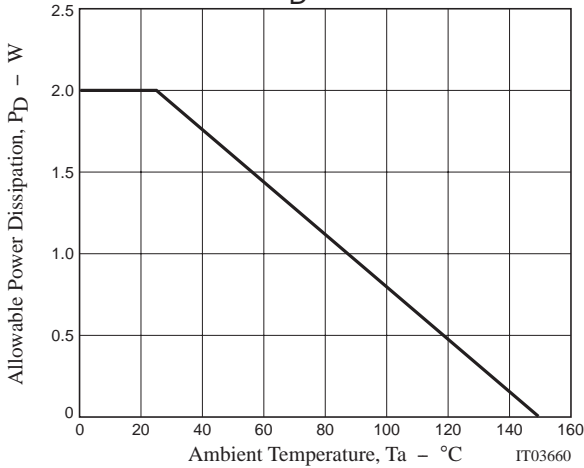
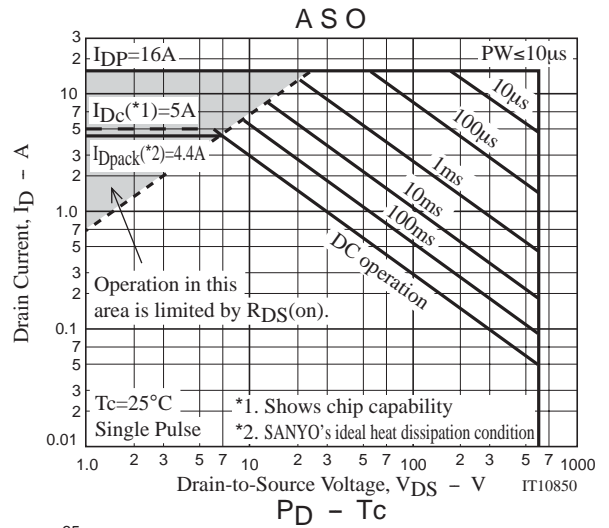
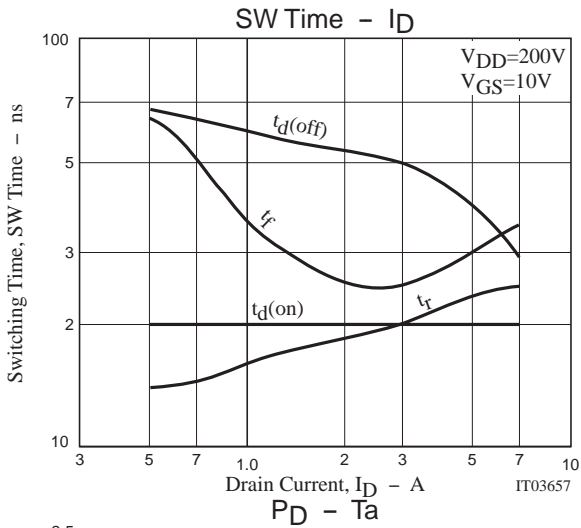
Avalanche Resistance Test Circuit



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Note on usage : Since the 2SK2625ALS is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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